

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	("20040201813").PN.	US-PGPUB; USPAT	OR	OFF	2005/04/25 15:33
S7	83	(photo adj2 spacer\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 15:52
S8	199	(photo\$5 adj2 spacer\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:46
S9	475373	spacer\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 15:51
S10	21110	(electrode\$5 adj2 pad\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:52
S11	12	("4422731"   "5177627"   "5499128"   "5504601"   "5517343"   "5593802"   "5680187"   "5748266"   "5777713"   "5812232"   "5917572"   "5969784").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/25 16:11
S12	116	S8 not S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 16:36
S13	1216	S9 and S10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:48
S14	317	S13 and ((conductive adj film) (ITO))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:48

S15	184	S14 and (lcd (liquid adj crystal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:49
S17	30469	(electrode\$5 adj pad\$5) (conduct\$5 adj pad\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 21:01
S18	1627	S9 same ((photo photolitho photolithography photolithographic) adj2 (process method))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:55
S19	646	S9 with ((photo photolitho photolithography photolithographic) adj2 (process method))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 18:03
S20	21	S19 and S17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:56
S21	2182	S9 and S17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 17:56
S22	300	S19 and (conduct\$5 adj (film layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 18:05
S23	840	S21 and (conduct\$5 adj (film layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 18:05

S24	164	S23 and (lcd (liquid adj crystal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 18:09
S25	317	S21 and (lcd (liquid adj crystal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 18:13
S26	1	("6445437").PN.	US-PGPUB; USPAT	OR	OFF	2005/04/25 18:16
S27	1	("20020171800").PN.	US-PGPUB; USPAT	OR	OFF	2005/04/25 19:19
S28	1333	349/155.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 19:20
S29	1119	349/155.ccls. and spacer\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 22:08
S30	5	S29 and S17 and (conduct\$5 adj (film layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 19:22
S31	172	S29 and (conduct\$5 adj (film layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 19:22
S32	381	S29 and ((conduct\$5 adj (film layer)) (indium adj tin) ITO)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 20:42
S33	1	("6445437").PN.	US-PGPUB; USPAT	OR	OFF	2005/04/25 19:56

S34	12	("4422731"   "5177627"   "5499128"   "5504601"   "5517343"   "5593802"   "5680187"   "5748266"   "5777713"   "5812232"   "5917572"   "5969784").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/25 19:56
S35	382	S29 and ((conduct\$5 adj (film layer)) (indium adj tin) ITO (conduct\$5 adj pad\$5) (electrode\$5 adj pad\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 20:45
S36	31	S19 and S35	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 20:45
S37	229	S9 and (((conduct\$5 adj (film layer)) (common adj electrode)) with ((electrode\$5 adj pad\$5) (conduct\$5 adj pad\$5)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 21:25
S38	260	(common adj electrode) with ((electrode adj pad\$5) (common adj2 pad\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 21:13
S39	50	S38 and S9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 21:23
S40	23	((((conduct\$5 adj (film layer)) (common adj electrode)) with ((electrode\$5 adj pad\$5) (conduct\$5 adj pad\$5)))) same ((lower adj substrate) (bottom adj substrate) (TFT adj substrate) (thin adj film adj transistor adj substrate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 21:59
S41	1600	((((conduct\$5 adj (film layer)) (common adj electrode)) with ((electrode\$5 adj pad\$5) (conduct\$5 adj pad\$5))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 22:00
S43	76	S41 and "349"/\$.ccls.	US-PGPUB; USPAT	OR	ON	2005/04/25 22:08

S45	8	349/155.ccls. and (spacer\$5 and ((electrode\$5 adj pad\$5) (conduct\$5 adj pad\$5)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/25 22:09
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